Diode Semiconductor Device - Page 1 of 1



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In	closure Material:	
G	ass	
0	verall Length:	
	840 inches	
Te	erminal Length:	
0.	500 inches	
M	ounting Method:	
Te	erminal	
Fe	eatures Provided:	
He	ermetically sealed case	
Se	emiconductor Material:	
Si	licon	
Vo	oltage Rating In Volts Per Characteristic:	
15	i2.0 reverse voltage, dc	
С	urrent Rating Per Characteristic:	
20	0.00 milliamperes forward current, average peak	
Po	ower Rating Per Characteristic:	
50	0.0 watts small-signal input power, common-collector preset	
M	aximum Operating Tempurature Per Measurement Point:	
17	5.0 degrees celsius junction	
Te	erminal Type And Quantity:	
2	tab, solder lug	
SI	nelf Life:	
N/	a	
U	nit Of Measure:	
De	emilitarization:	
No	)	
Fi	ig:	
A	10a0	
A	10a0	